

Notice of References Cited

Application/Control No.

09/712,190

Applicant(s)/Patent Under
Reexamination
KIM, WOONG-KWON

Examiner

HOAN C. NGUYEN

Art Unit

2871

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*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Name	Classification	
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NON-PATENT DOCUMENTS

Include as applicable: Author, Title Date, Publisher, Edition or Volume, Pertinent Pages)

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*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).)
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